100V N-CHANNEL ENHANCEMENT MODE MOSFET
POWERDI®

Product Summary

$V_{(BR)DSS}$	$R_{DS(ON)}$ max	I_D max T_A = +25°C
100V	80mΩ @ V_{GS} = 10V	4.2A
	99mΩ @ V_{GS} = 6.0V	3.6A

Features and Benefits

- Low $R_{DS(ON)}$ – ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Description

This MOSFET has been designed to minimize the on-state resistance ($R_{DS(on)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

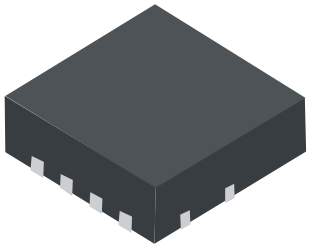
Mechanical Data

- Case: POWERDI3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram
- Terminals: Finish — Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.034 grams (approximate)

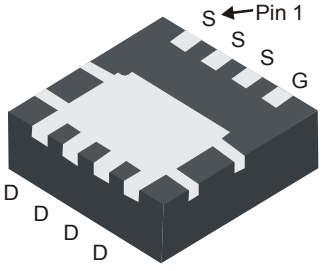
Applications

- Power Management Functions
- DC-DC Converters

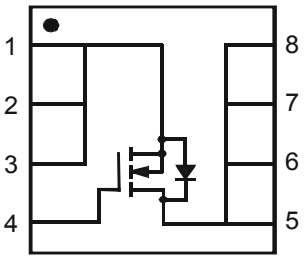
POWERDI3333-8



Top View



Bottom View



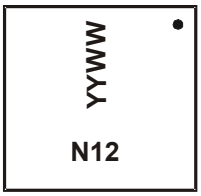
Top View
Internal Schematic

Ordering Information (Note 4)

Part Number	Compliance	Case	Packaging
DMN10H099SFG-7	Standard	POWERDI3333-8	2000/Tape & Reel
DMN10H099SFG-13	Standard	POWERDI3333-8	3000/Tape & Reel

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



N12 = Product Type Marking Code
YYWW = Date Code Marking
YY = Last digit of year (ex: 13 = 2013)
WW = Week code (01 ~ 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V_{DSS}	100	V
Gate-Source Voltage			V_{GSS}	±20	V
Continuous Drain Current (Note 6) V_{GS} = 10V	Steady State	T_A = +25°C T_A = +70°C	I_D	4.2 3.3	A
	t<10s	T_A = +25°C T_A = +70°C	I_D	5.8 4.5	A
Continuous Drain Current (Note 6) V_{GS} = 6V	Steady State	T_A = +25°C T_A = +70°C	I_D	3.6 2.9	A
	t<10s	T_A = +25°C T_A = +70°C	I_D	5.2 4.1	A
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I_{DM}	20	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)	T_A = +25°C	P_D	0.98	W
	T_A = +70°C		0.57	
Thermal Resistance, Junction to Ambient (Note 5)	Steady state	$R_{\theta JA}$	131	°C/W
	t<10s		76	
Total Power Dissipation (Note 6)	T_A = +25°C	P_D	2.31	W
	T_A = +70°C		1.18	
Thermal Resistance, Junction to Ambient (Note 6)	Steady state	$R_{\theta JA}$	55	°C/W
	t<10s		28	
Thermal Resistance, Junction to Case (Note 6)		$R_{\theta JC}$	6.9	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV_{DSS}	100	-	-	V	V_{GS} = 0V, I_D = 250µA
Zero Gate Voltage Drain Current	I_{DSS}	-	-	1.0	µA	V_{DS} = 80V, V_{GS} = 0V
Gate-Source Leakage	I_{GSS}	-	-	±100	nA	V_{GS} = ±20V, V_{DS} = 0V
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	$V_{GS(th)}$	1.5	2.0	3.0	V	V_{DS} = V_{GS}, I_D = 250µA
Static Drain-Source On-Resistance	$R_{DS\ (ON)}$	-	54	80	mΩ	V_{GS} = 10V, I_D = 3.3A
		-	58	99		V_{GS} = 6.0V, I_D = 3.0A
Forward Transfer Admittance	$\|Y_{fs}\|$	-	13	-	S	V_{DS} = 10V, I_D = 3.3A
Diode Forward Voltage	V_{SD}	-	0.77	-	V	V_{GS} = 0V, I_S = 3.2A
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C_{iss}	-	1172	-	pF	V_{DS} = 50V, V_{GS} = 0V, f = 1.0MHz
Output Capacitance	C_{oss}	-	40.8	-	pF	
Reverse Transfer Capacitance	C_{rss}	-	31.3	-	pF	
Gate Resistance	R_g	-	1.6	-	Ω	V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz
Total Gate Charge V_{GS} = 10V	Q_g	-	25.2	-	nC	V_{DS} = 50V, I_D = 3.3A
Total Gate Charge V_{GS} = 4.5V	Q_g	-	12.2	-	nC	
Gate-Source Charge	Q_{gs}	-	5.3	-	nC	
Gate-Drain Charge	Q_{gd}	-	5.9	-	nC	
Turn-On Delay Time	$t_{D(on)}$	-	5.4	-	ns	V_{GS} = 10V, V_{DS} = 50V, R_G = 6.0Ω, I_D = 3.3A
Turn-On Rise Time	t_r	-	5.9	-	ns	
Turn-Off Delay Time	$t_{D(off)}$	-	20.0	-	ns	
Turn-Off Fall Time	t_f	-	7.3	-	ns	

Notes:
5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to product testing.

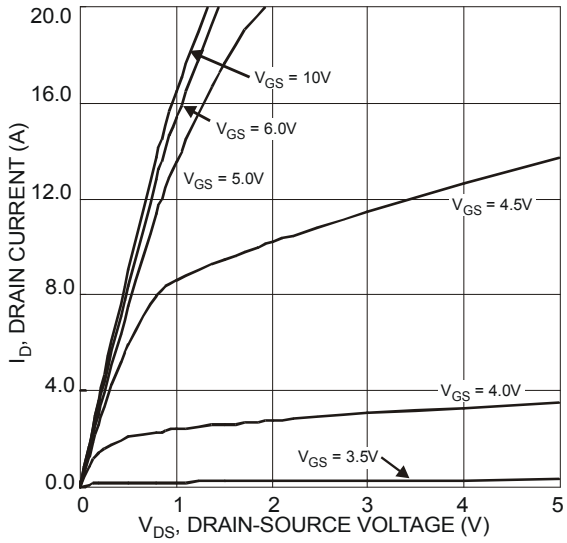


Figure 1 Typical Output Characteristic

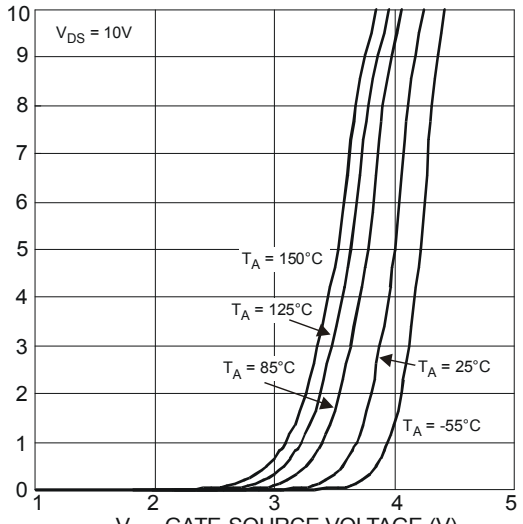


Figure 2 Typical Transfer Characteristics

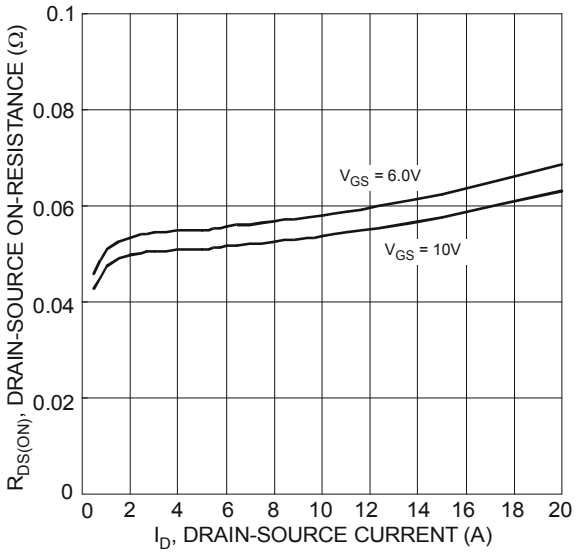


Figure 3 Typical On-Resistance vs. Drain Current and Gate Voltage

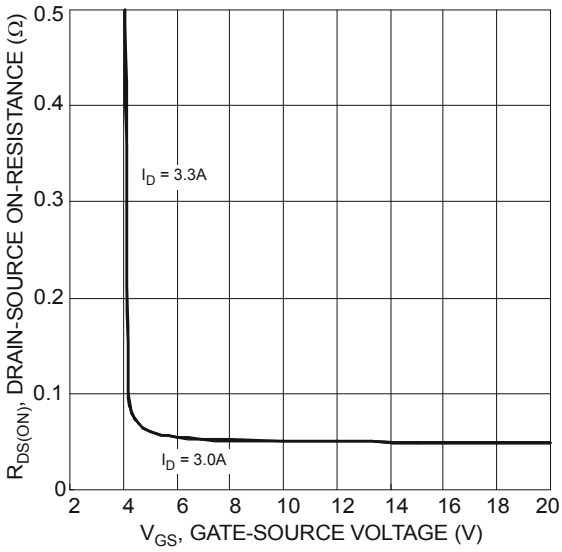


Figure 4 Typical Drain-Source On-Resistance vs. Gate-Source Voltage

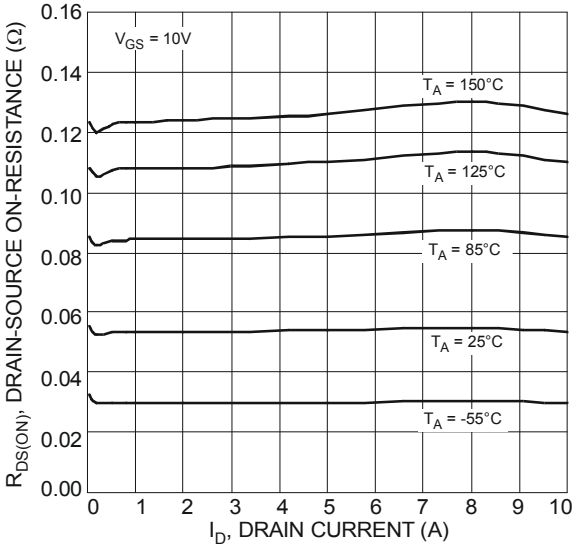


Figure 5 Typical On-Resistance vs. Drain Current and Temperature

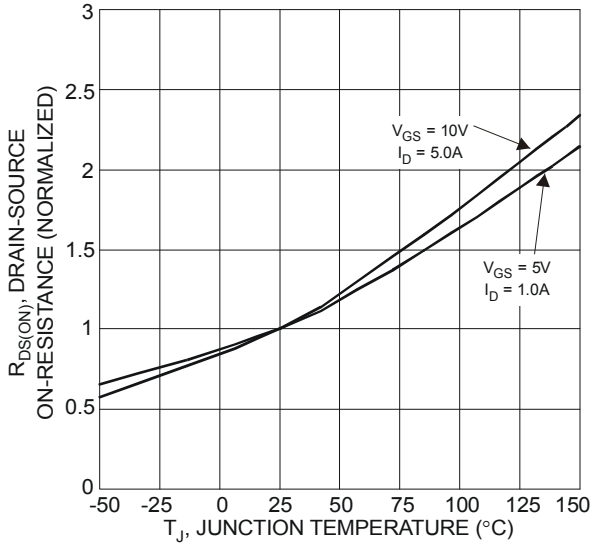


Figure 6 On-Resistance Variation with Temperature

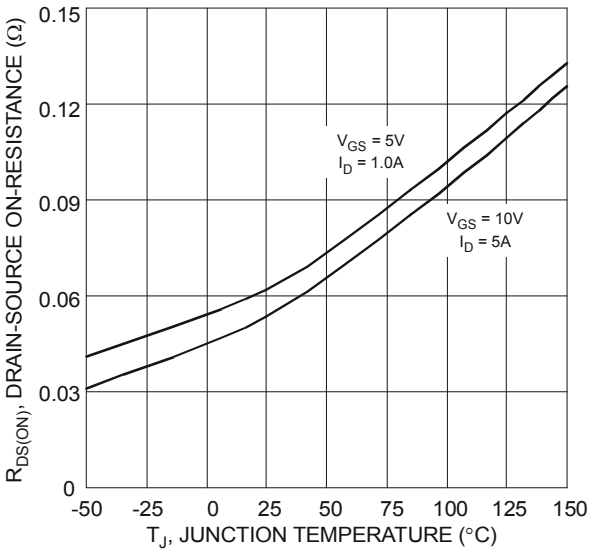


Figure 7 On-Resistance Variation with Temperature

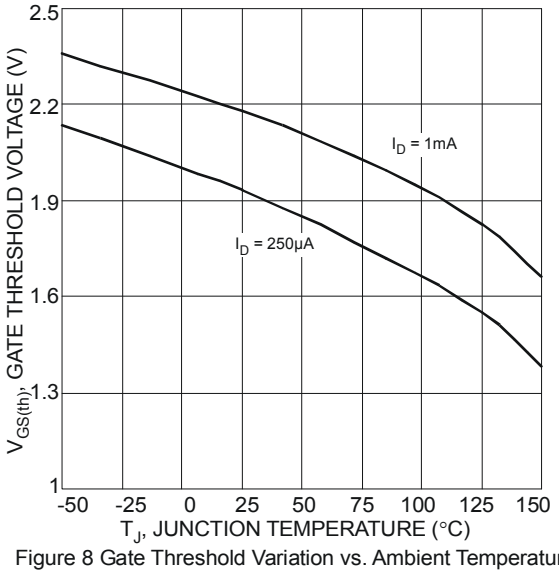


Figure 8 Gate Threshold Variation vs. Ambient Temperature

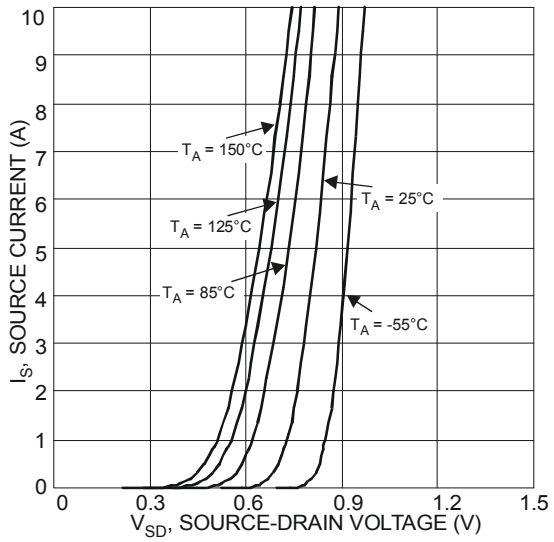


Figure 9 Diode Forward Voltage vs. Current

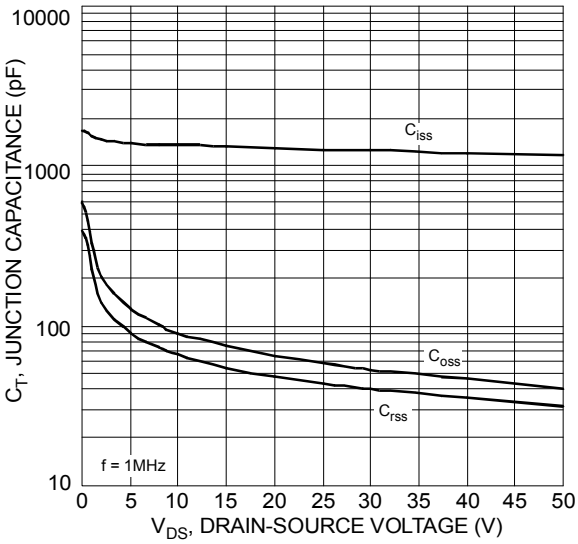


Figure 10 Typical Junction Capacitance

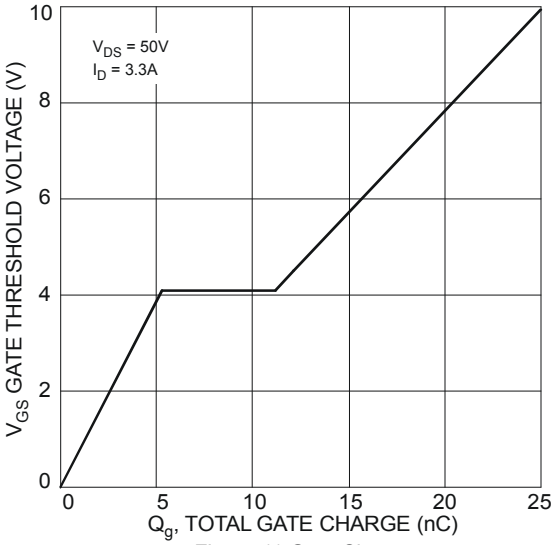


Figure 11 Gate Charge

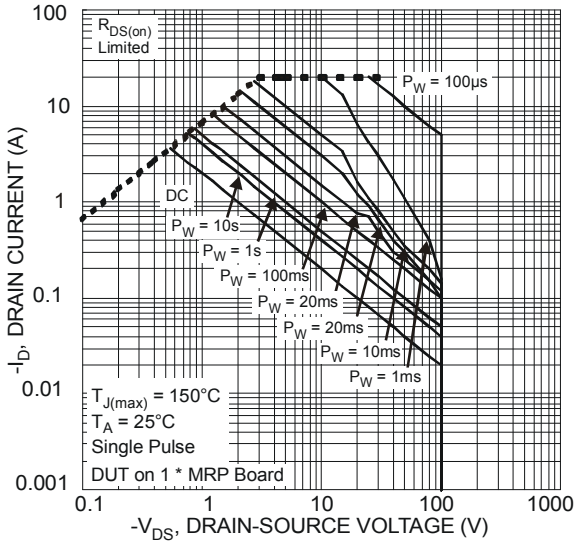


Figure 12 SOA, Safe Operation Area

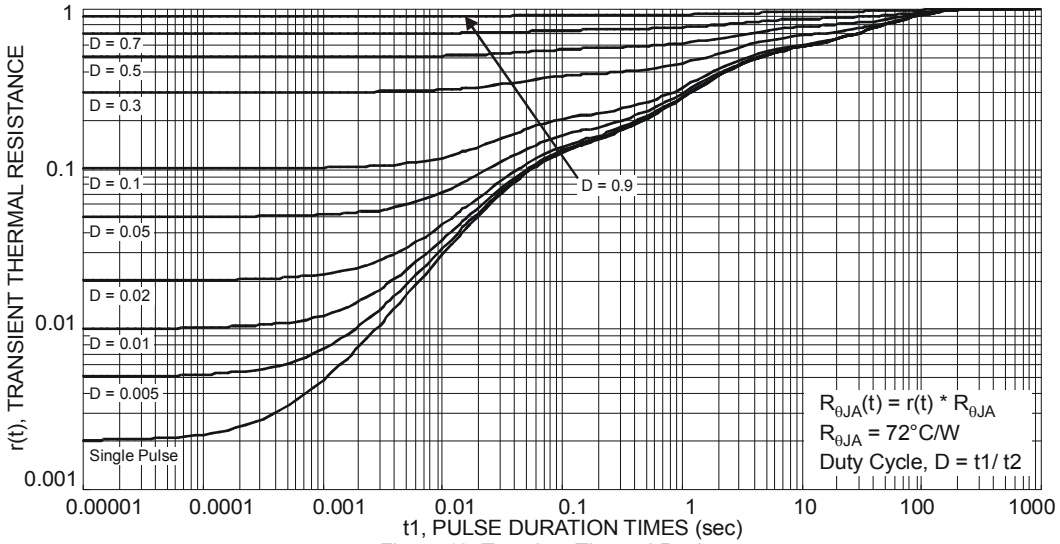
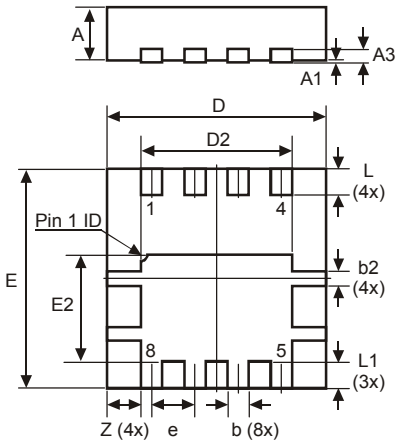


Figure 13 Transient Thermal Resistance

Package Outline Dimensions

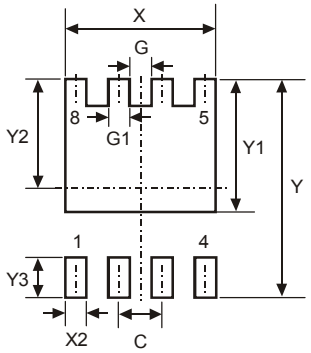
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



POWERDI3333-8			
Dim	**Min**	**Max**	**Typ**
D	3.25	3.35	3.30
E	3.25	3.35	3.30
D2	2.22	2.32	2.27
E2	1.56	1.66	1.61
A	0.75	0.85	0.80
A1	0	0.05	0.02
A3	–	–	0.203
b	0.27	0.37	0.32
b2	–	–	0.20
L	0.35	0.45	0.40
L1	–	–	0.39
e	–	–	0.65
Z	–	–	0.515
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
C	0.650
G	0.230
G1	0.420
Y	3.700
Y1	2.250
Y2	1.850
Y3	0.700
X	2.370
X2	0.420

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